L Number	Hits	Search Text	DB	Time stamp
-	235	(semiconductor near laser) and substrate and grating and (insulat\$	USPAT;	2001/10/81 14:04
		or nonconductor or non adj conductor or isolat\$) and electrode and	US-PGPUB;	
		(groove or grind or pace or rut\$ or rote) and clad\$	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	172	((semiconductor near laser) and substrate and grating and (insulat\$	USPAT;	2001/11/01 09:07
		or nonconductor or non adj conductor or isolat\$) and electrode and	US-PGPUB;	
		(groove or grind or pace or rut\$ or rote) and clad\$) and 372/\$	EPO; JPO;	
			DERWENT;	
	_	//	IBM_TDB	0001/11/01 00 10
	7	((semiconductor near laser) and (substrate near (layer or medium or	USPAT; US-PGPUB;	2001/11/01 09:18
		film or region)) and grating and (layer near (insulat\$ or nonconductor or non adj conductor or isolat\$)) and (electrode near	EPO; JPO;	
		(layer or medium or film or region)) and (groove or grind or pace or	DERWENT;	
		rut\$ or rote) and (clad\$ near (layer or medium or film or region)))	IBM_TDB	
		and 372/\$	10.11_100	
-	86	((semiconductor near laser) and substrate and grating and (insulat\$	USPAT;	2001/11/01 11:31
	00	or nonconductor or non adj conductor or isolat\$) and electrode and	US-PGPUB;	2001/11/01 11/01
		(groove or grind or pace or rut\$ or rote) and clad\$) and \$72/\$ and	EPO; JPO;	
		(waveguide near (layer or film or medium or region))	DERWENT;	
			IBM_TDB	
-	4	(((semiconductor near laser) and (substrate near (layer or medium or	USPAT;	2001/11/01 09:17
		film or region)) and grating and (layer near (insulat\$ or	US-PGPUB;	
		nonconductor or non adj conductor or isolat\$)) and (electrode near	ЕРО; ЈРО;	
		(layer or medium or film or region)) and (groove or grind or pace or	DERWENT;	
		rut\$ or rote) and (clad\$ near (layer or medium or film or region)))	IBM_TDB	
		and 372/\$) and (waveguide near (layer or film or medium or region))		:
-	47	(((semiconductor near laser) and substrate and grating and (insulat\$	USPAT;	2001/11/01 09:26
		or nonconductor or non adj conductor or isolat\$) and electrode and	US-PGPUB;	
		(groove or grind or pace or rut\$ or rote) and clad\$) and \$72/\$ and	EPO; JPO;	
		(waveguide near (layer or film or medium or region))) and 372/96	DERWENT;	
			IBM_TDB	
	4	(semiconductor near laser) and (substrate near layer) and grating	USPAT;	2001/11/01 09:29
		and (layer near (insulat\$ or nonconductor or non adj conductor or	US-PGPUB;	
		isolat\$)) and (electrode near layer) and (groove) and (clad\$ near	EPO; JPO;	
		layer) and 372/\$ and (waveguide near (layer or film or medium or	DERWENT;	
-	4	region)) (semiconductor near laser) and (substrate near layer) and grating	IBM_TDB USPAT;	2001/11/01 09:35
	Ŧ	and (layer near (insulat\$ or nonconductor or non adj conductor or	US-PGPUB;	2001/11/01 09:33
		isolat\$)) and (electrode near layer) and (groove) and (clad\$ near	EPO; JPO;	
		layer) and 372/\$ and (waveguide near layer)	DERWENT;	
		ayor, and one, and (waveguate near layer,	IBM_TDB	
-	40	((((semiconductor near laser) and substrate and grating and (insulat\$	USPAT;	2001/11/01 09:58
		or nonconductor or non adj conductor or isolat\$) and electrode and	US-PGPUB;	
		(groove or grind or pace or rut\$ or rote) and clad\$) and 372/\$ and	EPO; JPO;	
		(waveguide near (layer or film or medium or region))) and 372/96)	DERWENT,	
		and (waveguide near layer)	IBM_TDB	
-	8	(semiconductor near laser) and substrate and (grating same (insulat\$	USPAT;	2001/11/01 15:51
		or nonconductor or non adj conductor or isolat\$) with (groove or	US-PGPUB;	
		grind or pace or rut\$ or rote)) and electrode and clad\$ and 372/\$	EPO; JPO;	
		and (waveguide near (layer or film or medium or region)) and	DERWENT;	
İ		372/96 and (waveguide near layer)	IBM_TDB	
-	6	((semiconductor near laser) and substrate and (grating same	USPAT;	2001/11/01 13:26
		(insulat\$ or nonconductor or non adj conductor or isolat\$) with	US-PGPUB;	
		(groove or grind or pace or rut\$ or rote)) and electrode and clad\$	EPO; JPO;	
		and \$72/\$ and (waveguide near (layer or film or medium or region))	DERWENT;	
	_	and 372/96 and (waveguide near layer)) and resonator	IBM_TDB	0001/11/01/02
-	2	(semiconductor near laser) and substrate and (grating same (insulat\$	USPAT;	2001/11/01 16:02
-		or nonconductor or non adj conductor or isolat\$) with (groove or	US-PGPUB;	
	į			
		grind or pace or rut\$ or rote) same resonator) and electrode and clad\$ and 372/\$ and (waveguide near (layer or film or medium or	EPO; JPO; DERWENT;	